

Assignment - 6

Quantum Hall effect (QHE)

Ex 1.4 (S-Dutta)

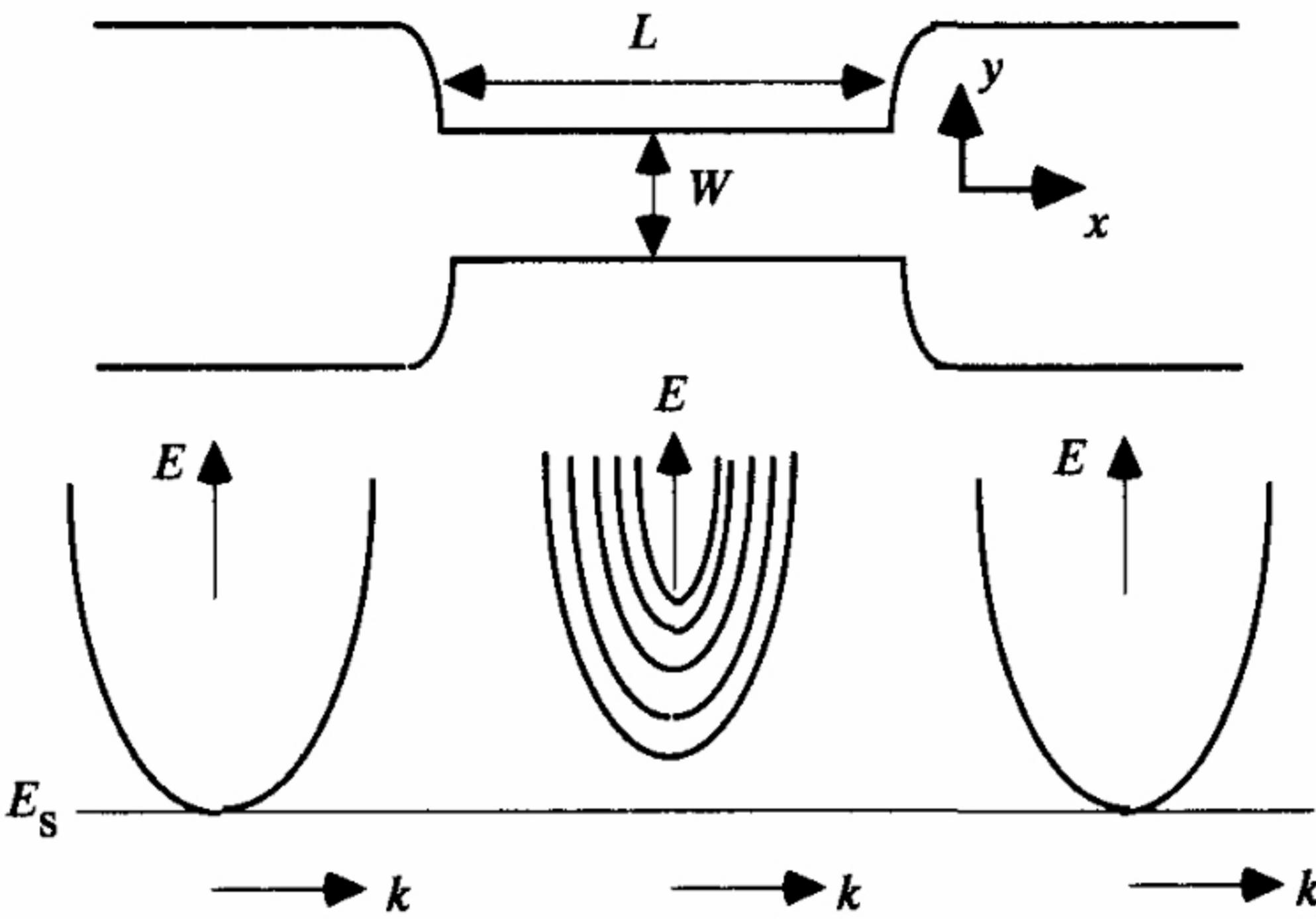


Fig. E.1.3. Narrow conductor etched out of a wide conductor. In the wide regions the transverse modes are essentially continuous, but in the narrow region the modes are well-separated in energy.

We have two wide 2D conductors on the left and right side of the etched narrow conductor. The parabolic confinement in y dir^M is given by :

$$U(y) = \frac{1}{2} m \omega_0^2 y^2, \text{ where } \omega_0 = \left(\frac{8E_F}{m} \right)^{1/2} \times \frac{1}{\omega},$$

$$E_{n,k} = E_s + \left(n + \frac{1}{2} \right) \hbar \omega + \frac{\hbar^2 k_x^2}{2m^*} \frac{\omega_0^2}{\omega^2} - E_{1.4}$$

$$\omega^2 = \omega_0^2 + \omega_c^2, \quad \omega_c^2 = \left(\frac{eB}{m^*} \right)^2$$

$B \rightarrow$ magnetic field in z-dir

Find no: of transverse modes as a function of magnetic field, B , assuming:

- (a) constant Fermi surface
- (b) constant electron density

Solution :

The number states in the etched conductor per unit length, n_L :

$$n_L = \frac{1}{L} \times 2 \times \frac{\text{Total volume occupied by modes in } k\text{-space}}{\text{Volume occupied by 1 state in } k\text{-space}}$$

$$= \frac{1}{L} \times 2 \times \sum_{i=1}^{i_{\max}} \frac{k_{xi}}{2\pi/\chi} \quad -①$$

where i_{\max} denotes maximum no: of modes that can be occupied. From Eq. E1.4 :

$$k_{xi} = \frac{1}{\hbar} \frac{1}{w_0} \sqrt{2m^*(E_f - E_s - (i + \frac{1}{2})\hbar\omega)} \quad -②$$

Substituting ② in ① :

$$n_L = \frac{1}{\pi \hbar} \sum_{i=1}^{i_{\max}} \frac{\omega}{\omega_0} \left[\sqrt{2m^* (E_f - E_s - (i + \frac{1}{2}) \hbar \omega)} \right]$$

Taking a factor of $\frac{\omega}{\omega_0}$ outside the root:

$$n_L = \frac{1}{\pi \hbar} \left(\frac{\omega}{\omega_0} \right)^{3/2} \sum_{i=1}^{i_{\max}} \sqrt{\frac{2m^*(E_f - E_s - (i + \frac{1}{2}) \hbar \omega_0)}{\omega/\omega_0}}$$

Let $E_1 = \frac{\hbar^2 \pi^2}{2 m \omega^2}$. Multiplying & dividing by $\sqrt{E_1}$,

$$n_L = \frac{1}{\pi \hbar} \left(\frac{\omega}{\omega_0} \right)^{3/2} \cdot \sqrt{E_1} \sum_{i=1}^{i_{\max}} \sqrt{\frac{E_f - E_s - (i + \frac{1}{2}) \hbar \omega_0}{\omega_0 E_1}}$$

$$= \frac{1}{\pi \hbar} \left(\frac{\omega}{\omega_0} \right)^{3/2} \cdot \frac{\pi \hbar}{\sqrt{2m \omega}} \sum_{i=1}^{i_{\max}} \sqrt{\frac{E_f - E_s - (i + \frac{1}{2}) \hbar \omega_0}{\omega_0 E_1}}$$

$$\Rightarrow \frac{\Omega_L \cdot W}{(\omega/\omega_0)^{3/2}} = \sum_{i=1}^{i_{\max}} \sqrt{\frac{E_f - E_S - \left(i + \frac{1}{2}\right) \hbar \omega_0}{\omega/\omega_0 E_1}}$$

(a) $E_f = \text{const}$, we need to find greatest integer, i_{\max} s.t:

$$\left(i_{\max} + \frac{1}{2}\right) \hbar \omega \leq E_f - E_S$$

$$\Rightarrow i_{\max} \leq \frac{E_f - E_S}{\hbar \omega} - \frac{1}{2}$$

No: of modes, M is $i_{\max} + 1$ as i_{\max} ranges from 0 to n $\in \mathbb{N}$.

$$\Rightarrow M \leq \frac{E_f - E_S}{\hbar \omega} + \frac{1}{2} \Rightarrow M = \left[\frac{E_f - E_S + \frac{1}{2}}{\hbar \omega} \right]$$

where $[\cdot]$ is the greatest integer function.

$$\hbar\omega_0 = 3.9 \text{ meV}, m^* = 0.067 m_0$$

M	$\hbar n_L$ bounds	$B(T)$
4	$4.9 \text{ meV} > \hbar n_L > 3.9 \text{ meV}$	$1.7T > B$
3	$6.9 \text{ meV} > \hbar n_L > 4.9 \text{ meV}$	$3.3T > B > 1.7T$
2	$11.5 \text{ meV} > \hbar n_L > 6.9 \text{ meV}$	$6.2T > B > 3.3T$
1	$14.4 \text{ meV} > \hbar n_L > 11.5 \text{ meV}$	$19.7T > B > 6.2T$
0	$\hbar n_L > 34.4 \text{ meV}$	$> 19.7T$

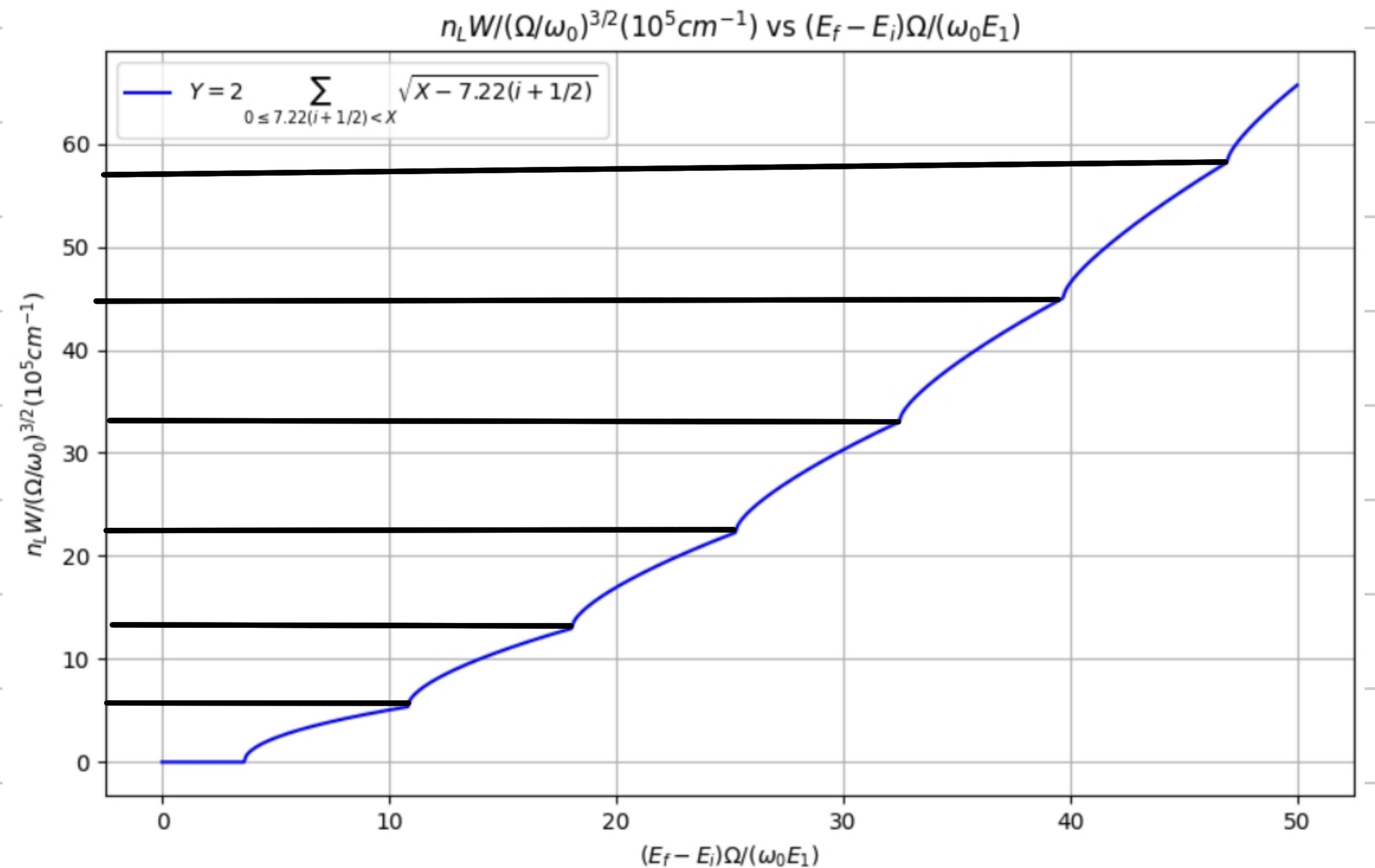
This works only
for small conductors

(b) Electron density n_L is constant. Hence LHS is constant.

$$\frac{n_L \cdot W}{(\Omega/\omega_0)^{3/2}} = \sum_{i=1}^{i_{\max}} \sqrt{\frac{E_f - E_s - (i + \frac{1}{2}) \frac{\hbar \omega_0}{E_1}}{\Omega/\omega_0 E_1}}$$

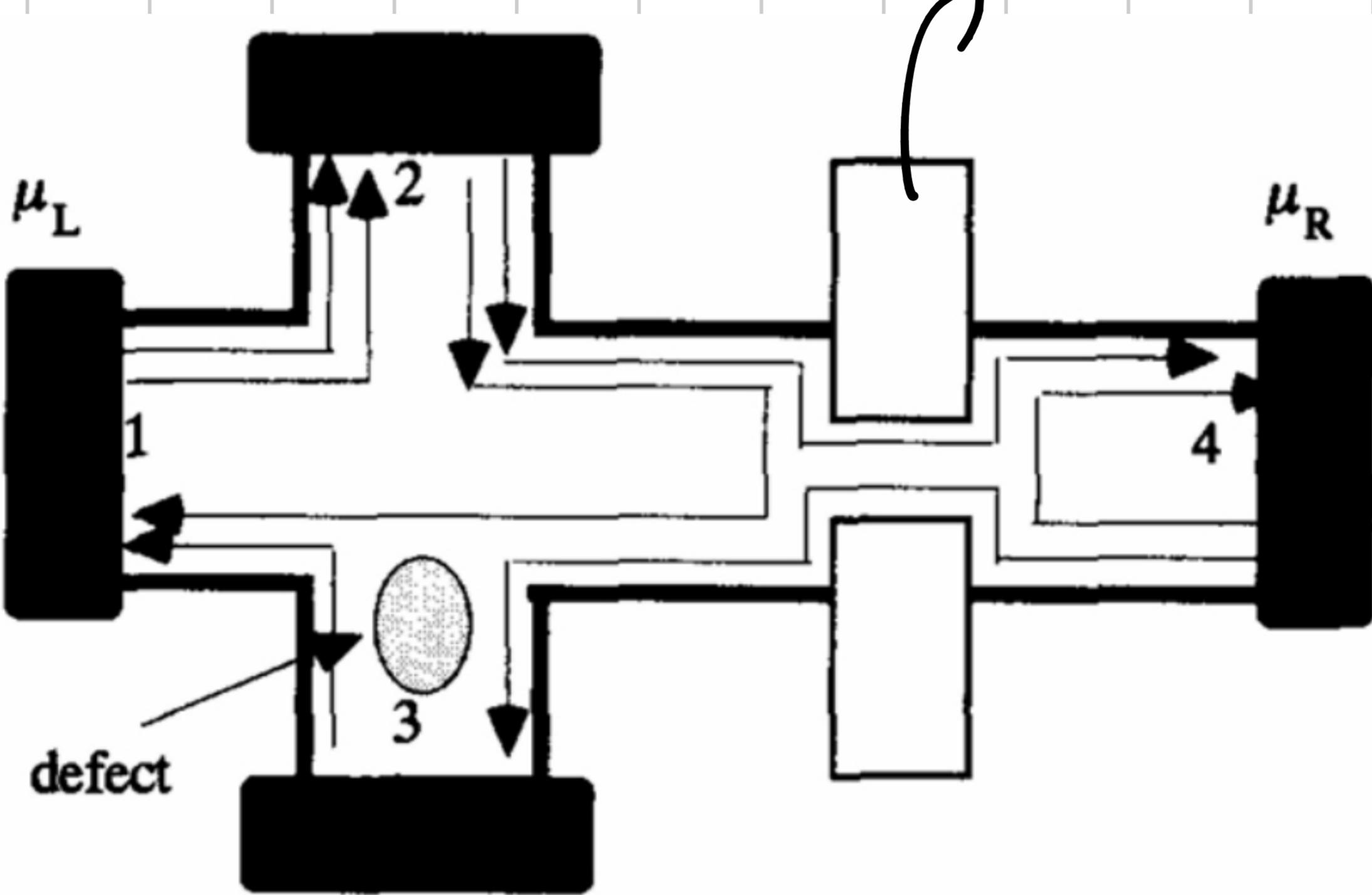
This means we have to calculate the no: of modes from the plot b/w $\frac{n_L \cdot W}{(\Omega/\omega_0)^{3/2}} = v$.

(in Tesla)



M=1	$0 < v < 5$	$B > 10.2$
M=2	$5 < v < 13$	$5 < B < 10.2$
M=3	$13 < v < 22$	$3.1 < B < 5$
M=4	$22 < v < 33$	$1.9 < B < 3.1$
M=5	$33 < v < 45$	$0.9 < B < 1.9$
M=6	$45 < v < 58$	$B < 0.9$

4.2.1 (Dutta)



scatter gates : allow some N modes to transmit out of M total modes

A Quantum Hall setup

$$M - N \quad m$$

Let $\mu_L = \mu_4 = 0$. We have $\mu_3 = \mu_2 = 0 \wedge \mu_1 = \mu_R$

Use

$$I_p = \sum_{q \neq p} G_{p \leftarrow q} (\mu_p - \mu_q)$$

to show that

$$R_H = \frac{h}{2e^2 M} \frac{1}{1-p} \quad \text{where } p = \frac{M-N}{M}$$

Solution :-

$$T_k = \frac{2e^2 M}{h} \sum_{q \neq k} T_{k \leftarrow q} (V_k - V_q)$$

The defect only sees the outer edge states if it goes directly to 1.
The remaining edges bypass it & go directly to 1.

T_{kq}	$q=1$	2	3	4
$k=1$	0	$\left(\frac{M-N}{M}\right)$	$\frac{N}{M}$	0
$k=2$	1	0	0	0
$k=3$	0	0	$\frac{M-N}{M}$	$\frac{N}{M}$
$k=4$	0	$\frac{N}{M}$	0	$\frac{M-N}{M}$

This is done to make sum of rows & columns = 1.

$I_2 = 0 = I_3$ as 2 & 3 are voltage probes
 $V_2 = V_1$, $V_3 = V_4$ as in Hall setup the
 edge modes equilibriamize the potential.

$$\begin{aligned}
 I_1 &= \frac{2e^2}{h} \cdot M \left[T_{12}(V_1 - V_2) + T_{13}(V_1 - V_3) + T_{14}(V_1 - V_4) \right] \\
 &= \frac{2e^2}{h} M \left[\frac{N}{M} (V_2 - V_3) + 0 \right]
 \end{aligned}$$

$$I_1 = \frac{2e^2}{h} M (1-p)(V_2 - V_3)$$

$$R_H = \frac{V_2 - V_3}{I_1} = \frac{h}{2e^2 M} \times \frac{1}{1-p}$$